

Data Sheet

September 1998

File Number

er 2894.3

# 20MHz, High Slew Rate, Uncompensated, High Input Impedance, Operational Amplifiers

HA-2520/2522/2525 comprise a series of operational amplifiers delivering an unsurpassed combination of specifications for slew rate, bandwidth and settling time. These dielectrically isolated amplifiers are controlled at close loop gains greater than 3 without external compensation. In addition, these high performance components also provide low offset current and high input impedance.

120V/µs slew rate and 200ns (0.2%) settling time of these amplifiers make them ideal components for pulse amplification and data acquisition designs. These devices are valuable components for RF and video circuitry requiring up to 20MHz gain bandwidth and 2MHz power bandwidth. For accurate signal conditioning designs the HA-2520/2522/2525's superior dynamic specifications are complemented by 10nA offset current,  $100M\Omega$  input impedance and offset trim capability. MIL-STD-883 product and data sheets are available upon request.

# Ordering Information

| PART NUMBER<br>(BRAND) | TEMP.<br>RANGE (°C) | PACKAGE         | PKG.<br>NO. |  |  |  |  |  |  |  |
|------------------------|---------------------|-----------------|-------------|--|--|--|--|--|--|--|
| HA2-2520-2             | -55 to 125          | 8 Pin Metal Can | T8.C        |  |  |  |  |  |  |  |
| HA2-2522-2             | -55 to 125          | 8 Pin Metal Can | T8.C        |  |  |  |  |  |  |  |
| HA2-2525-5             | 0 to 75             | 8 Pin Metal Can | T8.C        |  |  |  |  |  |  |  |
| HA3-2525-5             | 0 to 75             | 8 Ld PDIP       | E8.3        |  |  |  |  |  |  |  |
| HA7-2520-2             | -55 to 125          | 8 Ld CERDIP     | F8.3A       |  |  |  |  |  |  |  |
| HA7-2525-5             | 0 to 75             | 8 Ld CERDIP     | F8.3A       |  |  |  |  |  |  |  |
| HA9P2525-5<br>(H25255) | 0 to 75             | 8 Ld SOIC       | M8.15       |  |  |  |  |  |  |  |

#### **Features**

| High Slew Rate                      | 120V/μs |
|-------------------------------------|---------|
| • Fast Settling                     | 200ns   |
| Full Power Bandwidth                | 2MHz    |
| Gain Bandwidth (A <sub>V</sub> ≥ 3) | . 20MHz |
| High Input Impedance                | . 100MΩ |
| Low Offset Current                  | 10nA    |

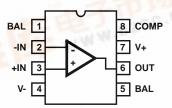
· Compensation Pin for Unity Gain Capability

# **Applications**

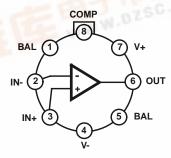
- Data Acquisition Systems
- RF Amplifiers
- Video Amplifiers
- · Signal Generators

## **Pinouts**

HA-2520 (CERDIP) HA-2525 (PDIP, CERDIP, SOIC) TOP VIEW



HA-2520/22/25 (METAL CAN) TOP VIEW





# HA-2520, HA-2522, HA-2525

## **Absolute Maximum Ratings**

#### 

## **Operating Conditions**

| Temperature Range |                |
|-------------------|----------------|
| HA-2520/2522-2    | -55°C to 125°C |
| HA-2525-5         | 0°C to 75°C    |

#### **Thermal Information**

| Thermal Resistance (Typical, Note 1)     | $\theta_{JA}$ (°C/W) | θ <sub>JC</sub> (°C/W)               |
|--|----------------------|--------------------------------------|
| Metal Can Package                        | 165                  | 80                                   |
| PDIP Package                             | 96                   | N/A                                  |
| CERDIP Package                           | 135                  | 50                                   |
| SOIC Package                             | 157                  | N/A                                  |
| Maximum Junction Temperature (Hermetic F | Packages)            | 175°C                                |
| Maximum Junction Temperature (Plastic P  | ackage)              | 150 <sup>o</sup> C                   |
| Maximum Storage Temperature Range        | 65                   | <sup>o</sup> C to 150 <sup>o</sup> C |
| Maximum Lead Temperature (Soldering 10   | Os)                  | 300°C                                |
| (SOIC - Lead Tips Only)                  |                      |                                      |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE

1.  $\theta_{JA}$  is measured with the component mounted on an evaluation PC board in free air.

# **Electrical Specifications** V<sub>SUPPLY</sub> = ±15V

|   | TEMP | HA-2520-2 |       |     | HA-2522-2 |       |     | HA-2525-5 |       |     |                    |
|---|------|-----------|-------|-----|-----------|-------|-----|-----------|-------|-----|--------------------|
|   | (°C) | MIN       | TYP   | MAX | MIN       | TYP   | MAX | MIN       | TYP   | MAX | UNITS              |
| INPUT CHARACTERISTICS                   | '    |           |       | I   |           | ı     |     |           |       |     | 1                  |
| Offset Voltage                          | 25   | -         | 4     | 8   | -         | 5     | 10  | -         | 5     | 10  | mV                 |
|   | Full | -         | -     | 11  | -         | -     | 14  | -         | -     | 14  | mV                 |
| Offset Voltage Drift                    | Full | -         | 20    | -   | -         | 25    | -   | -         | 30    | -   | μV/ <sup>o</sup> C |
| Bias Current                            | 25   | -         | 100   | 200 | -         | 125   | 250 | -         | 125   | 250 | nA                 |
|   | Full | -         | -     | 400 | -         | -     | 500 | -         | -     | 500 | nA                 |
| Offset Current                          | 25   | -         | 10    | 25  | -         | 20    | 50  | -         | 20    | 50  | nA                 |
|   | Full | -         | -     | 50  | -         | -     | 100 | -         | -     | 100 | nA                 |
| Input Resistance (Note 2)               | 25   | 50        | 100   | -   | 40        | 100   | -   | 40        | 100   | -   | МΩ                 |
| Common Mode Range                       | Full | ±10.0     | -     | -   | ±10.0     | -     | -   | ±10.0     | -     | -   | V                  |
| TRANSFER CHARACTERISTICS                | -    |           | 1     | I   |           |       | •   |           |       | ı   | 1                  |
| Large Signal Voltage Gain               | 25   | 10        | 15    | -   | 7.5       | 15    | -   | 7.5       | 15    | -   | kV/V               |
| (Notes 3, 6)                            | Full | 7.5       | -     | -   | 5         | -     |     | 5         | -     | -   | kV/V               |
| Common Mode Rejection Ratio (Note 4)    | Full | 80        | 90    | -   | 74        | 90    | -   | 74        | 90    | -   | dB                 |
| Gain Bandwidth (Notes 2, 5)             | 25   | 10        | 20    | -   | 10        | 20    | -   | 10        | 20    | -   | MHz                |
| Minimum Stable Gain                     | 25   | 3         | -     | -   | 3         | -     | -   | 3         | -     | -   | V/V                |
| OUTPUT CHARACTERISTICS                  | '    |           |       |     |           |       |     |           |       |     |                    |
| Output Voltage Swing (Note 3)           | Full | ±10.0     | ±12.0 | -   | ±10.0     | ±12.0 | -   | ±10.0     | ±12.0 | -   | V                  |
| Output Current (Note 6)                 | 25   | ±10       | ±20   | -   | ±10       | ±20   | -   | ±10       | ±20   | -   | mA                 |
| Full Power Bandwidth<br>(Notes 6, 11)   | 25   | 1.5       | 2.0   | -   | 1.2       | 2.0   | -   | 1.2       | 2.0   | -   | MHz                |
| TRANSIENT RESPONSE (A <sub>V</sub> = +3 | 3)   |           |       |     |           |       |     |           |       |     |                    |
| Rise Time (Notes 3, 7, 8, 10)           | 25   | -         | 25    | 50  | -         | 25    | 50  | -         | 25    | 50  | ns                 |
| Overshoot (Notes 3, 7, 8, 10)           | 25   | -         | 25    | 40  | -         | 25    | 50  | -         | 25    | 50  | %                  |
| Slew Rate (Notes 3, 7, 10, 12)          | 25   | ±100      | ±120  | -   | ±80       | ±120  | -   | ±80       | ±120  | -   | V/µs               |
| Settling Time (Notes 3, 7, 10, 12)      | 25   | -         | 0.20  | -   | -         | 0.20  | -   | -         | 0.20  | -   | μs                 |

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# HA-2520, HA-2522, HA-2525

# **Electrical Specifications** $V_{SUPPLY} = \pm 15V$ (Continued)

|                                       | TEMP<br>(°C) | HA-2520-2 HA-2522-2 |     |     | 2   | HA-2525-5 |     |     |     |     |       |
|---------------------------------------|--------------|---------------------|-----|-----|-----|-----------|-----|-----|-----|-----|-------|
| PARAMETER                             |              | MIN                 | TYP | MAX | MIN | TYP       | MAX | MIN | TYP | MAX | UNITS |
| POWER SUPPLY CHARACTERISTICS          |              |                     |     |     |     |           |     |     |     |     |       |
| Supply Current                        | 25           | -                   | 4   | 6   | -   | 4         | 6   | -   | 4   | 6   | mA    |
| Power Supply Rejection Ratio (Note 9) | Full         | 80                  | 90  | -   | 74  | 90        | -   | 74  | 90  | -   | dB    |

#### NOTES:

- 2. This parameter value is based on design calculations.
- 3.  $R_L = 2k\Omega$ .
- 4.  $V_{CM}^- = \pm 10V$ .
- 5.  $A_V > 10$ .
- 6.  $V_O = \pm 10.0 V_o$
- 7.  $C_L = 50pF$ .
- 8.  $V_0 = \pm 200 \text{mV}$ .
- 9.  $\Delta V = \pm 5.0 V$ .
- 10. See Transient Response Test Circuits and Waveforms.
- $\frac{\text{Slew Rate}}{2\pi \text{V}_{\text{PEAK}}}$ 11. Full Power Bandwidth guaranteed based on slew rate measurement using: FPBW =
- 12.  $V_{OUT} = \pm 5V$ .

#### Test Circuits and Waveforms

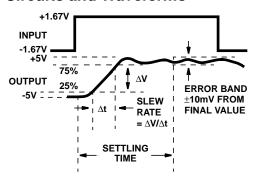
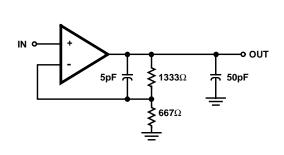
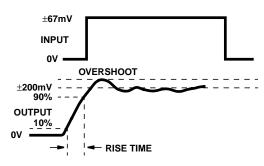


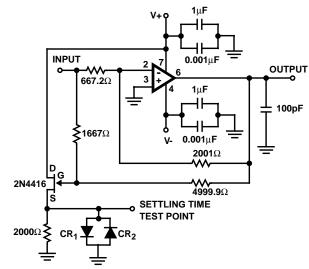
FIGURE 1. SLEW RATE AND SETTLING TIME





NOTE: Measured on both positive and negative transitions from 0V to +200mV and 0V to -200mV at the output.

**FIGURE 2. TRANSIENT RESPONSE** 



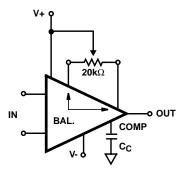
#### NOTES:

- 13.  $A_V = -3$ .
- 14. Feedback and summing resistor ratios should be 0.1% matched.
- 15. Clipping diodes CR<sub>1</sub> and CR<sub>2</sub> are optional. HP5082-2810 recommended.

FIGURE 4. SETTLING TIME TEST CIRCUIT

FIGURE 3. SLEW RATE AND TRANSIENT RESPONSE

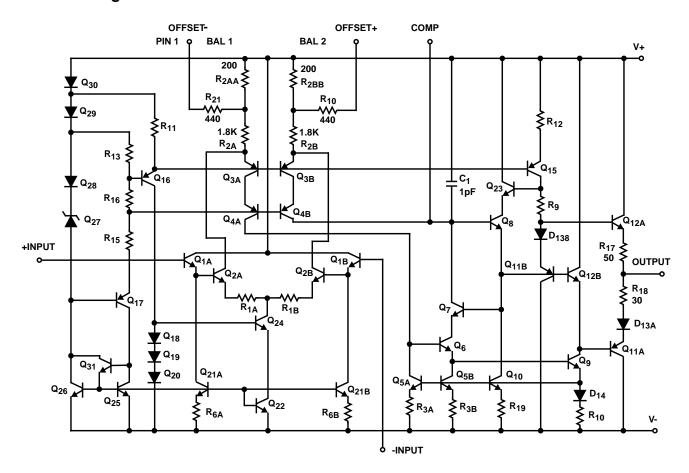
## Test Circuits and Waveforms (Continued)



NOTE: Tested offset adjustment range is  $|V_{OS} + 1mV|$  minimum referred to output. Typical ranges are  $\pm 20mV$  with  $R_T = 20k\Omega$ .

FIGURE 5. SUGGESTED VOS ADJUSTMENT AND COMPENSATION HOOK-UP

# Schematic Diagram



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## Typical Application

#### Inverting Unity Gain Circuit

Figure 6 shows a Compensation Circuit for an inverting unity gain amplifier. The circuit was tested for functionality with supply voltages from  $\pm 4V$  to  $\pm 15V$ , and the performance as tested was: Slew Rate ≈ 120V/µs; Bandwidth ≈ 10MHz; and Settling Time  $(0.1\%) \approx 500$ ns. Figure 7 illustrates the amplifier's frequency response, and it is important to note that capacitance at pin 8 must be minimized for maximum bandwidth.

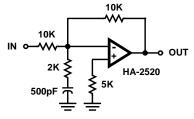


FIGURE 6. INVERTING UNITY GAIN CIRCUIT

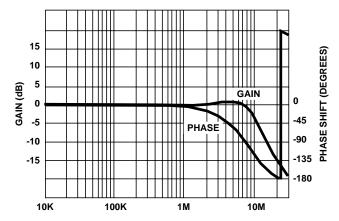


FIGURE 7. FREQUENCY RESPONSE FOR INVERTING UNITY **GAIN CIRCUIT** 

# **Typical Performance Curves** V<sub>S</sub> = ±15V, T<sub>A</sub> = 25°C, Unless Otherwise Specified

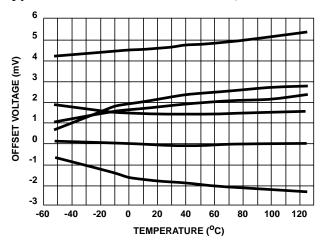


FIGURE 8. OFFSET VOLTAGE vs TEMPERATURE (6 TYPICAL **UNITS FROM 3 LOTS)** 

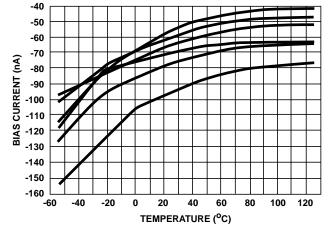


FIGURE 9. BIAS CURRENT vs TEMPERATURE (6 TYPICAL **UNITS FROM 3 LOTS)** 

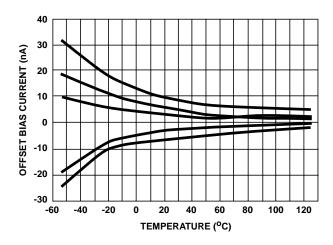


FIGURE 10. OFFSET CURRENT vs TEMPERATURE (5 TYPICAL **UNITS FROM 3 LOTS)** 

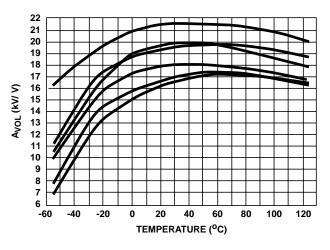


FIGURE 11. OPEN LOOP GAIN vs TEMPERATURE (6 TYPICAL **UNITS FROM 3 LOTS)** 

# Typical Performance Curves $V_S = \pm 15V$ , $T_A = 25^{\circ}C$ , Unless Otherwise Specified (Continued)

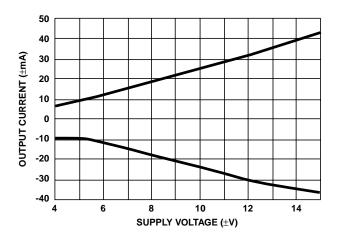


FIGURE 12. OUTPUT CURRENT vs SUPPLY VOLTAGE

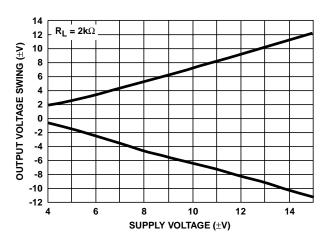


FIGURE 13. OUTPUT VOLTAGE SWING vs SUPPLY VOLTAGE

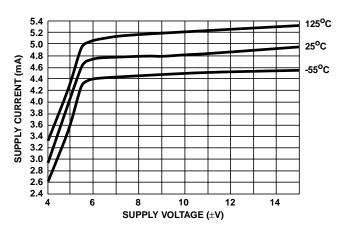


FIGURE 14. SUPPLY CURRENT vs SUPPLY VOLTAGE

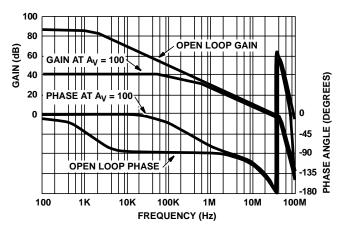


FIGURE 15. FREQUENCY RESPONSE

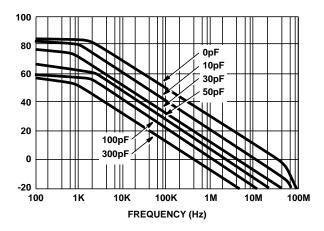


FIGURE 16. OPEN LOOP FREQUENCY RESPONSE FOR VARIOUS VALUES OF CAPACITORS FROM COMP PIN TO GROUND

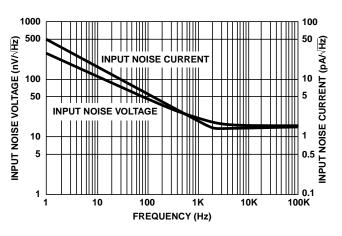


FIGURE 17. INPUT NOISE CHARACTERISTICS

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## Typical Performance Curves $V_S = \pm 15V$ , $T_A = 25^{\circ}C$ , Unless Otherwise Specified (Continued)

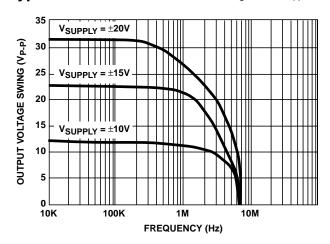


FIGURE 18. OUTPUT VOLTAGE SWING vs FREQUENCY

COMP

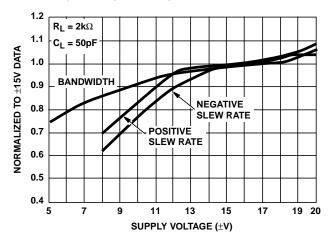


FIGURE 19. NORMALIZED AC PARAMETERS vs SUPPLY VOLTAGE

## Die Characteristics

#### **DIE DIMENSIONS:**

67 mils x 57 mils x 19 mils (1700µm x 1440µm x 483µm)

#### **METALLIZATION:**

Type: Al, 1% Cu Thickness: 16kÅ ±2kÅ

#### **SUBSTRATE POTENTIAL:**

Unbiased

#### **PASSIVATION:**

Type: Nitride (Si<sub>3</sub>N<sub>4</sub>) over Silox (SiO<sub>2</sub>, 5% Phos.)

Silox Thickness: 12kÅ ±2kÅ Nitride Thickness: 3.5kÅ ±1.5kÅ

#### TRANSISTOR COUNT:

40

OUT

#### PROCESS:

Bipolar Dielectric Isolation

## Metallization Mask Layout

HA-2520, HA-2522, HA-2525

BAL

